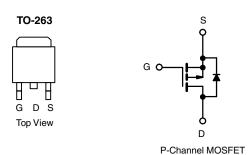


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Automotive P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	- 30				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0070				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0110				
I _D (A)	- 50				
Configuration	Single				



FEATURES

- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- 100 % R_q and UIS Tested
- AEC-Q101 Qualified^d
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912





ORDERING INFORMATION	
Package	TO-263
Lead (Pb)-free and Halogen-free	SQM50P03-07-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	- 30	V	
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Currenta	T _C = 25 °C	1	- 50		
Continuous Drain Current	T _C = 125 °C	- I _D	- 50		
Continuous Source Current (Diode Conduction)a	I _S	- 50	А		
Pulsed Drain Current ^b	I _{DM}	- 200			
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 50		
Single Pulse Avalanche Energy		E _{AS}	125	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	150	W	
iviaximum rowei bissipation	T _C = 125 °C	ı D	50		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	40	°C/W	
Junction-to-Case (Drain)		R_{thJC}	1	C/VV	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		-						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		- 30	-	-	- V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		- 2.0	- 2.5		
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = - 30 V	-	-	- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 125 °C	-	-	- 50	μA	
		V _{GS} = 0 V	V _{DS} = - 30 V, T _J = 175 °C	-	-	- 250		
On-State Drain Currenta	I _{D(on)}	V _{GS} = - 10 V	$V_{DS} \le -5 V$	- 120	-	-	Α	
		V _{GS} = - 10 V	I _D = - 30 A	-	0.0050	0.0070		
		V _{GS} = - 10 V	I _D = - 30 A, T _J = 125 °C	-	-	0.0102		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 30 A, T _J = 175 °C	-	-	0.0118	Ω	
		V _{GS} = - 4.5 V	I _D = - 20 A	-	0.0089	0.0110		
Forward Transconductanceb	9 _{fs}	V _{DS} = - 15 V, I _D = - 30 A		-	62	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	4304	5380	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = - 25 V, f = 1 MHz	-	764	955		
Reverse Transfer Capacitance	C _{rss}			-	680	850		
Total Gate Charge ^c	Q_{g}			-	103.5	155		
Gate-Source Charge ^c	Q_{gs}	V _{GS} = - 10 V	$V_{DS} = -15 \text{ V}, I_{D} = -75 \text{ A}$	-	14.3	-	nC	
Gate-Drain Charge ^c	Q _{gd}	7		-	26.9	-		
Gate Resistance	R _g	f = 1 MHz		1.4	2.85	4.3	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	11	17		
Rise Time ^c	t _r	V_{DD} = - 15 V, R_L = 0.2 Ω $I_D \cong$ - 75 A, V_{GEN} = - 10 V, R_g = 1 Ω		-	10	15	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	63	95		
Fall Time ^c	t _f			-	26	39		
Source-Drain Diode Ratings and Chara	acteristics ^b	•						
Pulsed Current ^a	I _{SM}			-	-	- 200	Α	
Forward Voltage	V_{SD}	I _F = - 45 A, V _{GS} = 0 V		-	- 0.9	- 1.5	V	

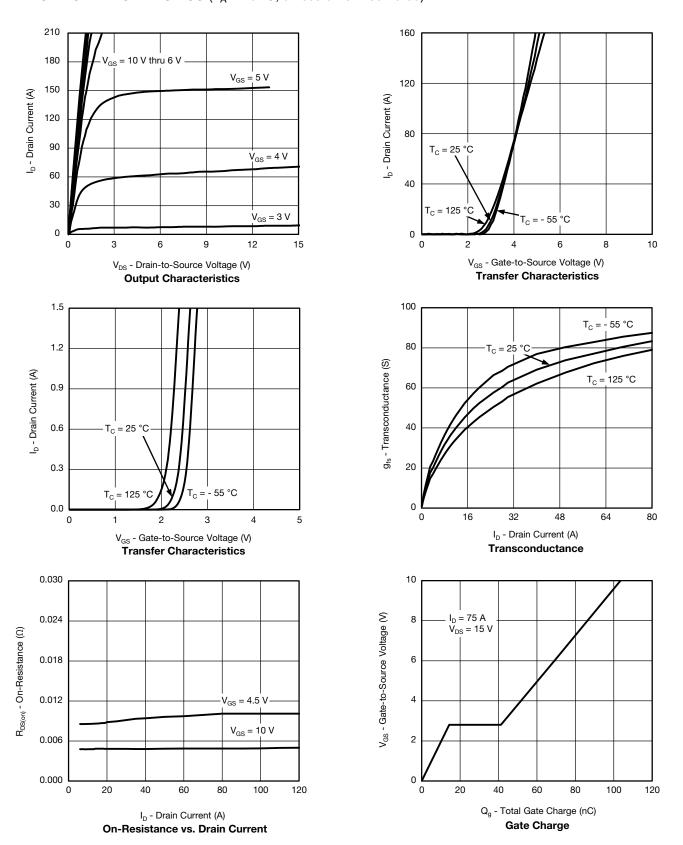
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

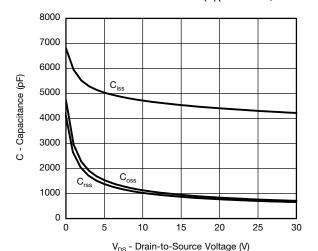


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

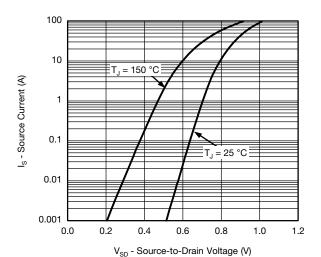




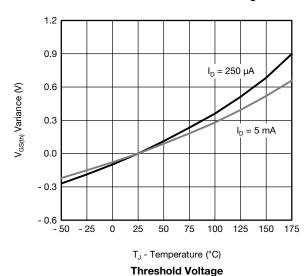
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

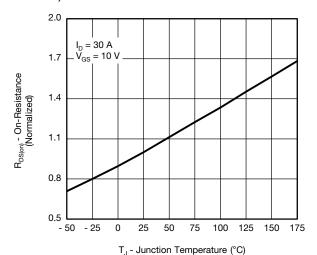


Capacitance

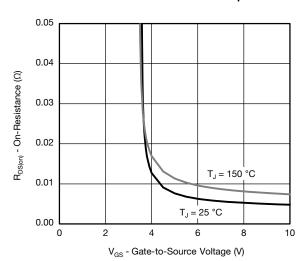


Source Drain Diode Forward Voltage

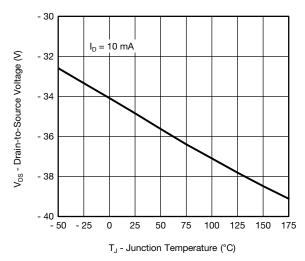




On-Resistance vs. Junction Temperature

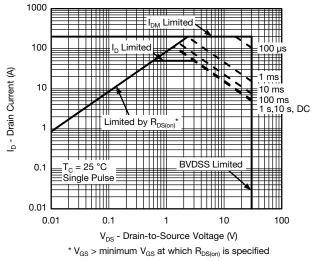


On-Resistance vs. Gate-to-Source Voltage

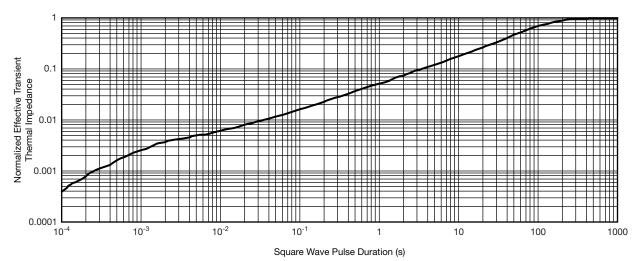


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



Safe Operating Area

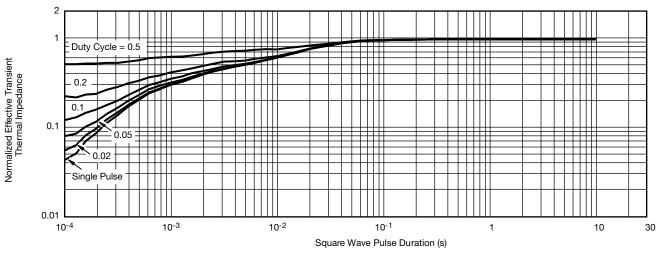


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

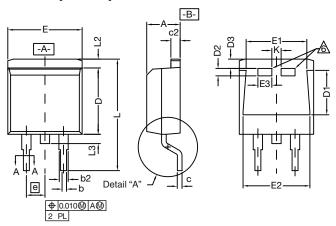
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

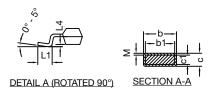
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67044.





TO-263 (D²PAK): 3-LEAD





		INCHES		MILLIN	METERS	
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
C*	Thin lead	0.013	0.018	0.330	0.457	
	Thick lead	0.023	0.028	0.584	0.711	
	Thin lead	0.013	0.017	0.330	0.431	
c1	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
E		0.380	0.410	9.652	10.414	
E1		0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
е		0.100 BSC		2.54 BSC		
K		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
M		-	0.002	-	0.050	
ECN: T10-0738-Rev. J, 03-Jan-11 DWG: 5843						

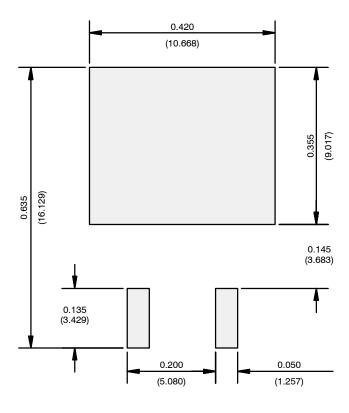
Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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